

**MJ2955 (See 2N3055)
MJ2955A
(See 2N3055A)**

**Medium-Power Complementary
Silicon Transistors**

... for use as output devices in complementary general purpose amplifier applications.

- High DC Current Gain — $h_{FE} = 4000$ (Typ) @ $I_C = 5.0$ Adc
- Monolithic Construction with Built-in Base-Emitter Shunt Resistors

MAXIMUM RATINGS

Rating	Symbol	MJ2500 MJ3000	MJ2501 MJ3001	Unit
Collector-Emitter Voltage	V_{CEO}	60	80	Vdc
Collector-Base Voltage	V_{CB}	60	80	Vdc
Emitter-Base Voltage	V_{EB}	5.0		Vdc
Collector Current	I_C	10		Adc
Base Current	I_B	0.2		Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	150 0.857		Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +200		$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	θ_{JC}	1.17	$^\circ\text{C/W}$

**PNP
MJ2500**

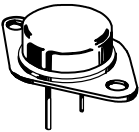
**MJ2501*
NPN**

MJ3000

MJ3001*

*Motorola Preferred Device

**10 AMPERE
DARLINGTON
POWER TRANSISTORS
COMPLEMENTARY
SILICON
60-80 VOLTS
150 WATTS**



**CASE 1-07
TO-204AA
(TO-3)**

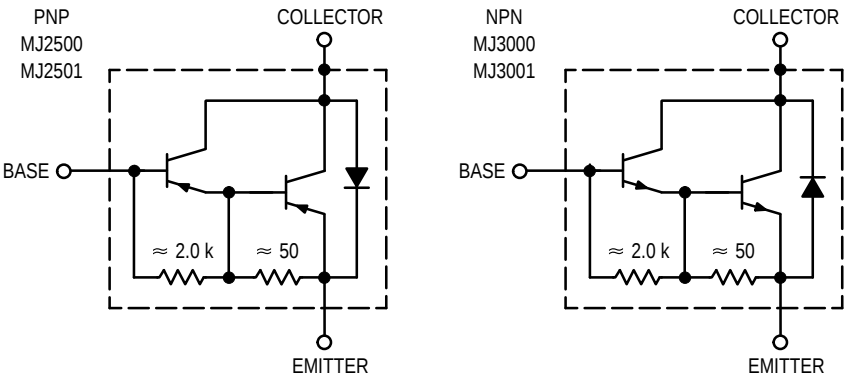


Figure 1. Darlington Circuit Schematic

Preferred devices are Motorola recommended choices for future use and best overall value.

REV 7

MJ2500 MJ2501 MJ3000 MJ3001

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector Emitter Breakdown Voltage ⁽¹⁾ ($I_C = 100\text{ mAdc}$, $I_B = 0$)	MJ2500, MJ3000 MJ2501, MJ3001	$V_{(BR)CEO}$	60 80	— —	Vdc
Collector–Emitter Leakage Current ($V_{EB} = 60\text{ Vdc}$, $R_{BE} = 1.0\text{ k ohm}$) ($V_{EB} = 80\text{ Vdc}$, $R_{BE} = 1.0\text{ k ohm}$) ($V_{EB} = 60\text{ Vdc}$, $R_{BE} = 1.0\text{ k ohm}$, $T_C = 150^\circ\text{C}$) ($V_{EB} = 80\text{ Vdc}$, $R_{BE} = 1.0\text{ k ohm}$, $T_C = 150^\circ\text{C}$)	MJ2500, MJ3000 MJ2501, MJ3001 MJ2500, MJ3000 MJ2501, MJ3001	I_{CER}	— — — —	1.0 1.0 5.0 5.0	mAdc
Emitter Cutoff Current ($V_{BE} = 5.0\text{ Vdc}$, $I_C = 0$)		I_{EBO}	—	2.0	mAdc
Collector Emitter Leakage Current ($V_{CE} = 30\text{ Vdc}$, $I_B = 0$) ($V_{CE} = 40\text{ Vdc}$, $I_B = 0$)	MJ2500, MJ3000 MJ2501, MJ3001	I_{CEO}	— —	1.0 1.0	mAdc
ON CHARACTERISTICS⁽¹⁾					
DC Current Gain ($I_C = 5.0\text{ Adc}$, $V_{CE} = 3.0\text{ Vdc}$)		h_{FE}	1000	—	—
Collector–Emitter Saturation Voltage ($I_C = 5.0\text{ Adc}$, $I_B = 20\text{ mAdc}$) ($I_C = 10\text{ Adc}$, $I_B = 50\text{ mAdc}$)		$V_{CE(sat)}$	— —	2.0 4.0	Vdc
Base Emitter Voltage ($I_C = 5.0\text{ Adc}$, $V_{CE} = 3.0\text{ Vdc}$)		$V_{BE(on)}$	—	3.0	Vdc

(1) Pulse Test: Pulse Width $\leq 300\text{ }\mu\text{s}$, Duty Cycle $\leq 2.0\%$.

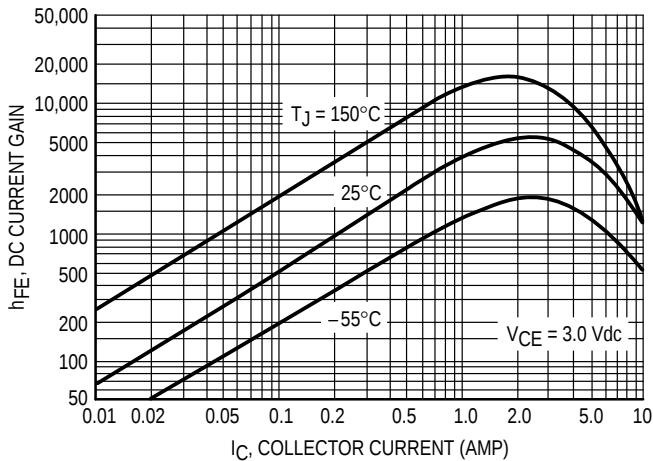


Figure 2. DC Current Gain

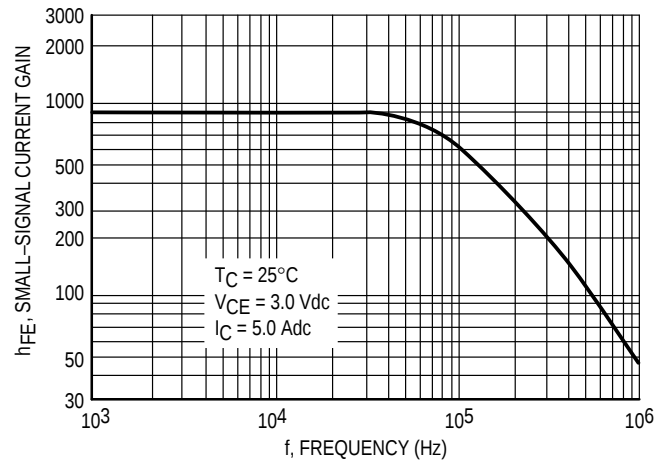


Figure 3. Small-Signal Current Gain

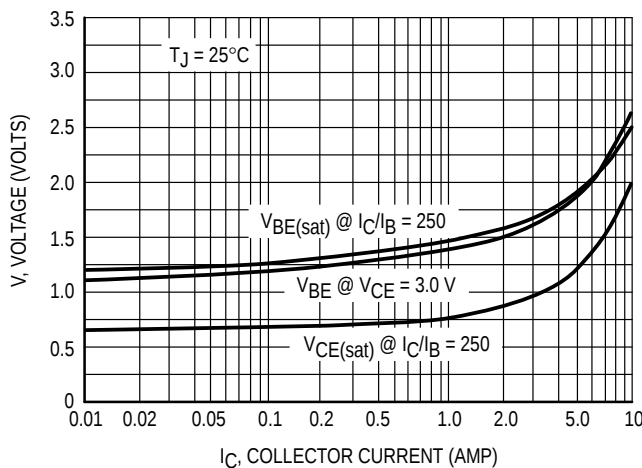


Figure 4. "On" Voltages

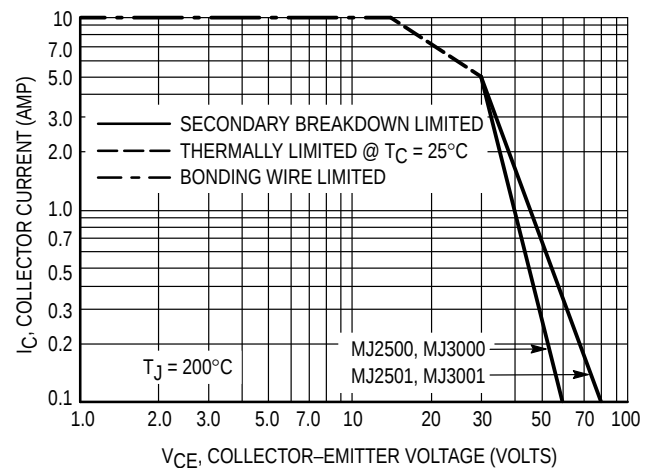


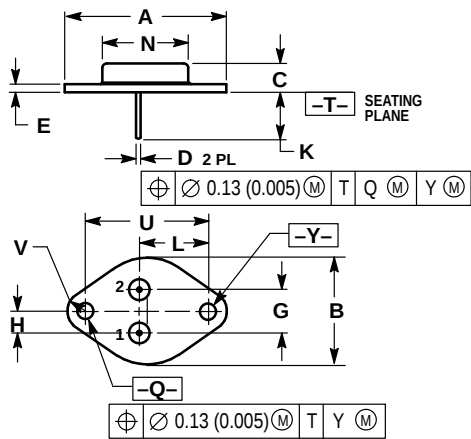
Figure 5. DC Safe Operating Area

There are two limitations on the power handling ability of a transistor: junction temperature and secondary breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; e.g., the transistor must not be subjected to greater dissipation

than the curves indicate.

At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by secondary breakdown.

PACKAGE DIMENSIONS



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.550 REF		39.37 REF	
B	—	1.050	—	26.67
C	0.250	0.335	6.35	8.51
D	0.038	0.043	0.97	1.09
E	0.055	0.070	1.40	1.77
G	0.430 BSC		10.92 BSC	
H	0.215 BSC		5.46 BSC	
K	0.440	0.480	11.18	12.19
L	0.665 BSC		16.89 BSC	
N	—	0.830	—	21.08
Q	0.151	0.165	3.84	4.19
U	1.187 BSC		30.15 BSC	
V	0.131	0.188	3.33	4.77

STYLE 1:
PIN 1. BASE
2. EMITTER
CASE: COLLECTOR

CASE 1-07
TO-204AA (TO-3)
ISSUE Z

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